Icemos Technology Ltd Product Specification 1000.494202 Issue Date 31 August 2021 09:03

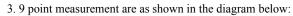
Part Number	Customer	

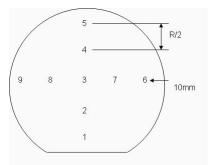
Category		Parameter	Specification	Measurement Method
OverallWafer	1.0	Diameter	100.00 +/- 0.50 mm	Wafer Vendor
	2.0	Primary Flat Orientation	<110> +/- 1 degree	Wafer Vendor
	3.0	Primary Flat Length	32.50 +/- 2.50 mm	Wafer Vendor
	4.0	Secondary Flat Orientation	none/semi	
	5.0	Overall Thickness	400.00 +/- 6.00 um	Guaranteed by Process
	6.0	Total Thickness Variation (TTV)	<5.00um	Guaranteed by Process
	7.0	Bow	<40.00um	Guaranteed by Process
	8.0	Warp	<40.00um	Guaranteed by Process
	9.0	Edge Exclusion	5 mm	Guaranteed by Process
	10.0	Silicon Supplier	IceMOS supplied handle and device silicon - FULL SERVICE	
HandleSilicon	11.0	Handle Growth Method	FZ	Wafer Vendor
	12.0	Handle Orientation	<100> +/- 0.5 degree	Wafer Vendor
	13.0	Handle Thickness	360.00 +/- 5.00 um	Guaranteed by Process
	14.0	Handle Doping Type	P	Wafer Vendor
	15.0	Handle Dopant	Boron	Wafer Vendor
	16.0	Handle Resistivity	1000 - 99999 Ohmcm	Wafer Vendor
	17.0	Backside Finish	Lapped/Etched with no oxide and lasermark	Guaranteed by process
DeviceSilicon	18.0	Device Growth Method	FZ	Wafer Vendor
	19.0	Device Orientation	<111> +/- 1.0 degree	Wafer Vendor
	20.0	Nominal Thickness	40.00 +/- 1.00 um	ADE Single Point, 100%
	21.0	Distance to device silicon edge from wafer edge	<= 2mm	Guaranteed by Process
	22.0	Device Doping Type	P	Wafer Vendor
	23.0	Device Dopant	Boron	Wafer Vendor
	24.0	Device Resistivity	1000 - 5000 Ohmcm	Wafer Vendor
	25.0	Voids		Guaranteed by Process, SAM inspection
	26.0	Haze	none	Guaranteed by Process, Bright LIght inspection
	27.0	Scratches	none	Guaranteed by Process, Bright LIght inspection

Page 1 of 2 22/06/2024 www.icemostech.com

Part Number		Customer		
Category	Parameter	Specification	Measurement Method	
Shipping Details	Wafer per box :	Max 25		
	Packaging:	Taped Polypropylene Wafer Box Empak, Ultrapak, 100.00mm Antistatic Double Bagging		
	Lot Shipment Data	Device Thickness Bow / Warp Data Handle and SOI Thickness		
Explanatory Notes	1. Microscope inspec	tion performed using microscope scan as below. 5x objective.		
	2. All bright light inspections performed exclude all wafer area outside the edge exclusion defined in Overall			

Wafer, Edge Exclusion. High intensity bright lamp inspection as per ASTM F523.





Additional Information